



## High Efficient Surface Mount Rectifiers

Reverse Voltage 50 to 1000 Volts Forward Current 2.0 Amperes

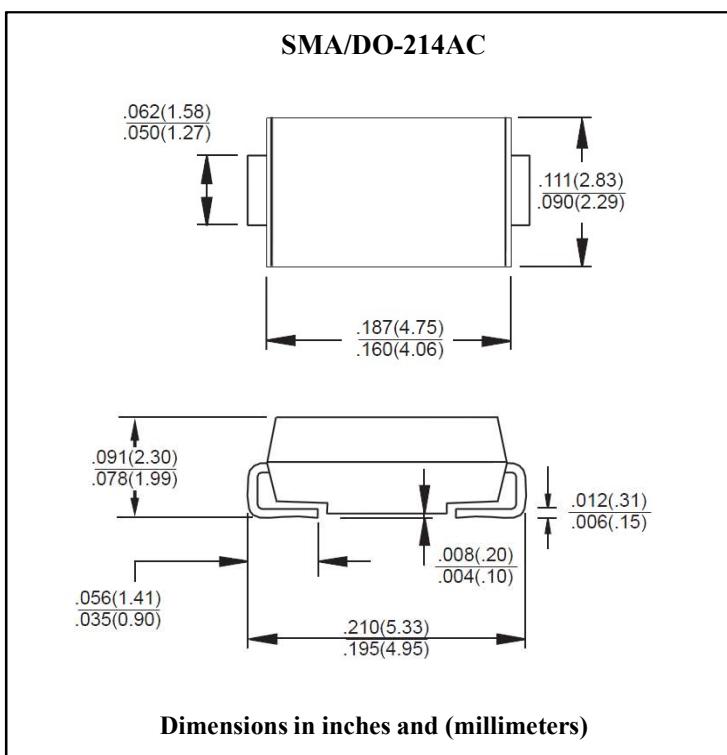
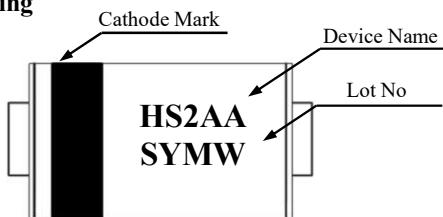
### Features

- For surface mounted application
- Glass passivated junction chip
- Low forward voltage drop
- Low profile package
- Built-in strain relief, ideal for automatic placement
- Fast switching for high efficiency
- Plastic material used carries underwriters laboratory classification 94V-O
- High temperature soldering : 260°C /10 seconds at terminals

### Mechanical Data

- Case : Molded plastic
- Terminals : Solder plated
- Polarity : Indicated by cathode band
- Weight : 0.064gram

### Marking



### Maximum Ratings & Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified

Single phase half wave 60 Hz, resistive or inductive load,  
for capacitive load, derate current by 20%

Parameter	Symbol	HS2AA	HS2BA	HS2DA	HS2FA	HS2GA	HS2JA	HS2KA	HS2MA	Unit	Remark				
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	V					
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	V					
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	V					
Maximum Average Forward Rectified Current See Fig.1	I <sub>F</sub> (AV)	2.0								A					
Peak Forward Surge Current 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	50								A					
Maximum Instantaneous Forward Voltage @ 2.0A	V <sub>F</sub>	1.0			1.3	1.7			V						
Maximum DC Reverse Current at Rated DC Blocking Voltage	I <sub>R</sub>	5.0								uA	Ta=25°C				
		100								uA	Ta=100°C				
Maximum Reverse Recovery Time	t <sub>rr</sub>	50				75				ns	Note 1				
Typical Junction Capacitance	C <sub>J</sub>	50				30				pF	Note 2				
Typical Thermal Resistance	R <sub>th(j-a)</sub>	80								°C /W	Note 3				
Operation Junction Temperature Range	T <sub>J</sub>	-55 to +150								°C					
Storage Temperature Range	T <sub>STG</sub>	-55 to +150								°C					

Note 1. Reverse Recovery Time Test Conditions : I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

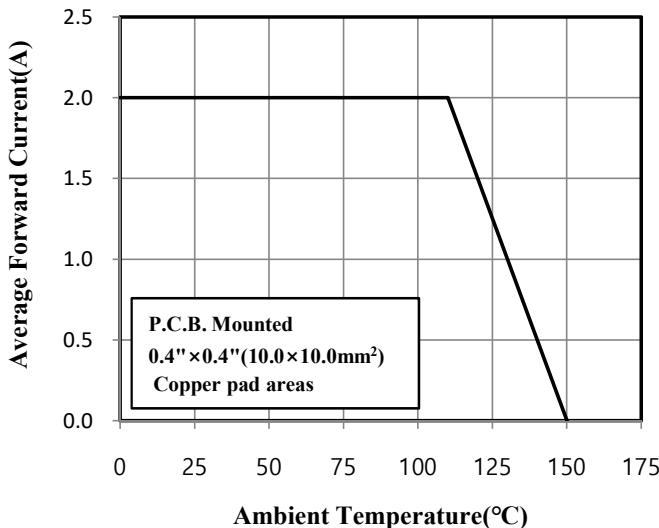
Note 2. Measured at 1MHz and Applied Reverse Voltage of 4.0Volts D.C.

Note 3. Mounted on P.C.B with 0.4"×0.4" (10mm×10mm) Copper Pad Areas

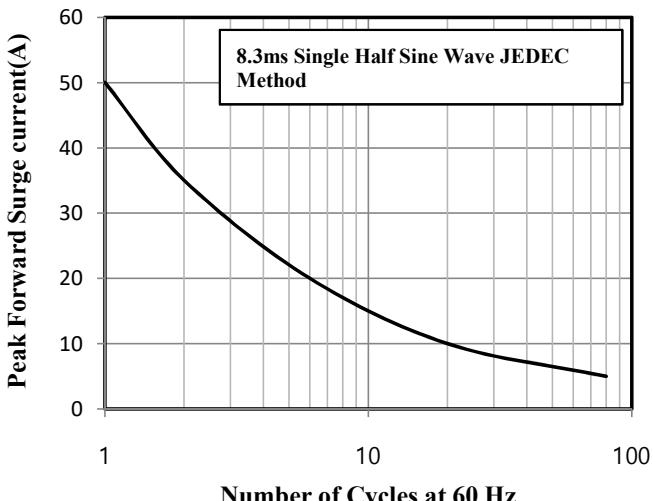


**Ratings and Characteristics Curves** (Ta=25°C unless otherwise noted)

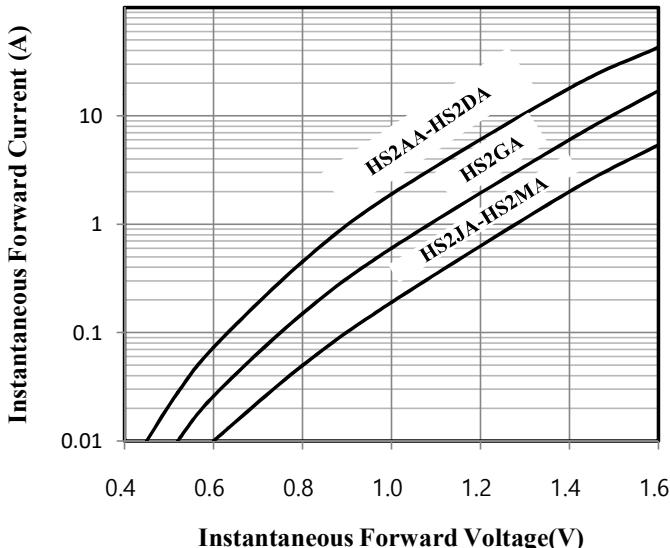
**Fig.1 Forward Current Derating Curve**



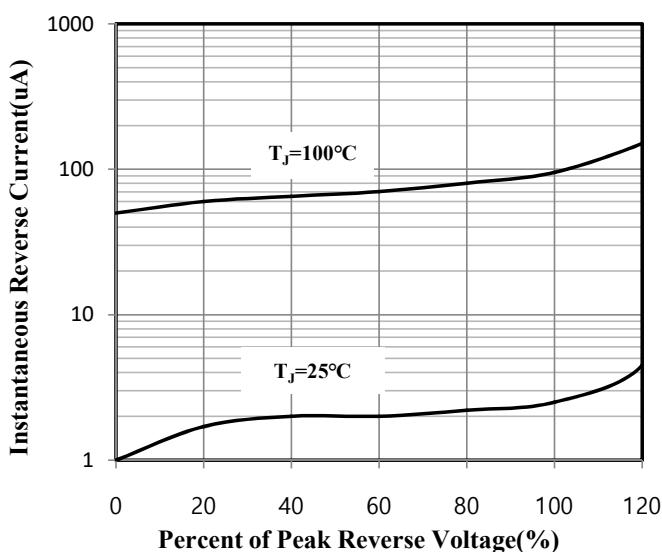
**Fig.2 Maximum Non-Repetitive Peak Forward Surge Current**



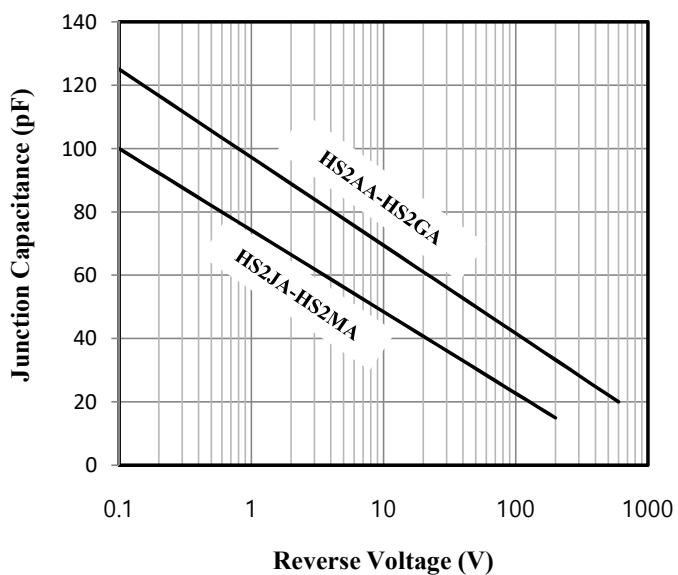
**Fig.3 Typical Instantaneous Forward Characteristics**



**Fig.5 Typical Reverse Characteristics**



**Fig.4 Typical Junction Capacitance**



**Fig. 6 Reverse Recovery Time Charateristic and Test Circuit Diagram**

